## NSN 5961-00-333-9652

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**Fiig:** A110a0



View Online at https://aerobasegroup.com/nsn/5961-00-333-9652 **Inclosure Material:** Metal **Overall Length:** 0.210 inches **Overall Diameter:** 0.230 inches **Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: T0-206aa **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 80.0 breakdown voltage, collector-to-emitter, base open and 4.5 breakdown voltage, emitter-to-base, collector open **Power Rating Per Characteristic:** 1.8 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnp **Test Data Document:** 07187-4008219 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No